IN THE CLAIMS:

Please amend the claims as follows:

Claims 1-13 (Cancelled).

Claim 14 (Currently Amended): An organic electro luminescent (EL) display device comprising:

a substrate ~~composed of~~ having an array unit and a ground unit;

a first insulating layer in the array unit;

an organic luminescent unit in the array unit and having a first electrode under the first insulating layer, an organic emitting layer on both the first electrode and the first insulating layer, a second insulating layer on both the organic emitting layer and the first insulating layer, and a second electrode on the second insulating layer;

a ground line in the ground unit; and

the second electrode of the organic luminescent unit directly connected to the ground line.

Claim 15 (Previously Presented): The organic EL display device of claim 14, wherein the first electrode is an anode electrode.

Claim 16 (Previously Presented): The organic EL display device of claim 14, wherein the second electrode is a cathode electrode.

Claim 17 (Currently Amended): The organic EL display device of claim 14, wherein the organic emitting layer ~~is composed of~~ includes an electron transport layer, an emitting layer, a hole transport layer, and a hole injection layer.

Claim 18 (Previously Presented): The organic EL display device of claim 14, wherein the second insulating layer is formed of at least one of LiF and LiO_2.

Claim 19 (Previously Presented): The organic EL display device of claim 14, wherein the second electrode is contacted to the ground line through a ground contact hole formed at the ground line.

Claim 20 (Previously Presented): The organic EL display device of claim 14, wherein the array unit further includes a thin film transistor and a capacitor.

Claim 21 (Previously Presented): The organic EL display device of claim 20, wherein the thin film transistor comprises:

an active layer including source/drain regions in which impurities are doped with high concentration and a channel region formed at a middle part thereof,

a gate electrode formed by forming a gate insulating layer on the channel region of the active layer; and

source and drain electrodes respectively connected to the source and drain regions.